

# CBCS SCHEME

17ELN15/25

First/Second Semester B.E. Degree Examination, Jan./Feb. 2023

## Basic Electronics

Time: 3 hrs.

Max. Marks: 100

Note: Answer any FIVE full questions, choosing ONE full question from each module.

### Module-1

- 1 a. Explain the operation of pn junction diode under forward and reverse bias condition. (07 Marks)
- b. A sinusoidal wave of  $v = 600 \sin 314t$  is applied to a halfwave rectifier. The  $R_L = 2 \text{ K}\Omega$  and  $R_F = 60 \Omega$ , find: (i)  $I_{dc}$  (ii)  $I_{rms}$  (iii)  $V_{dc}$  (iv) Efficiency  $\eta$  (05 Marks)
- c. Draw common emitter circuit. Sketch the input and output characteristics and briefly explain the three regions of operation. (08 Marks)

OR

- 2 a. With neat circuit diagram and waveforms, explain the working of full wave bridge rectifier. (08 Marks)
- b. Explain how Zener diode can be used as voltage regulator. (07 Marks)
- c. Obtain the relationship between  $\alpha_{dc}$  and  $\beta_{dc}$ . Calculate  $I_C$ ,  $I_E$  and  $\beta_{dc}$  for a transistor that has  $\alpha_{dc} = 0.9$  and  $I_B = 50 \mu\text{A}$ . (05 Marks)

### Module-2

- 3 a. With neat circuit diagram, explain the operation of base bias circuit with necessary equations. (08 Marks)
- b. What is op-amp? List the characteristics of an ideal op-amp. (06 Marks)
- c. For the circuit shown in Fig.Q3(c), find the output voltage  $V_o$ .

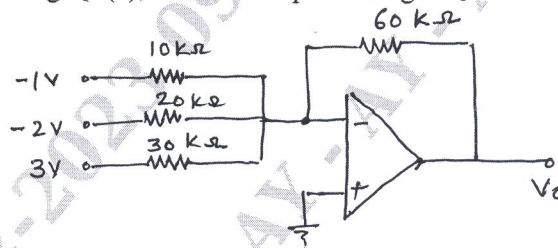


Fig.Q3(c)

(06 Marks)

OR

- 4 a. In the circuit shown in Fig.Q4(a), a silicon transistor with  $V_{BE} = 0.7 \text{ V}$ ,  $\beta = 50$  is used. Draw the DC load line and mark Q point.

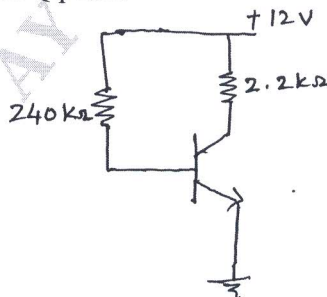


Fig.Q4(a)

(07 Marks)

- b. Explain how op-amp can be used as an integrator. Derive the expression for output voltage. (07 Marks)
- c. Draw and write output voltage expression for following circuits using op-amp:  
 (i) Inverting amplifier (ii) Voltage follower (iii) Differentiator (06 Marks)

**Module-3**

- 5 a. Perform the following:  
 (i)  $(37)_{10} = (?)_2 = (?)_8$   
 (ii)  $(10110101001.101101)_2 = (?)_{16} = (?)_{10}$  (08 Marks)
- b. Subtract  $(101011)_2$  from  $(111001)_2$  using 1's and 2's complements. (06 Marks)
- c. Simplify and realize using basic gates  $Y = \overline{ABC} + \overline{A}BC + A\overline{BC} + ABC$ . (06 Marks)

**OR**

- 6 a. State and prove De Morgan's theorems. (06 Marks)
- b. Simplify the following Boolean functions:  
 (i)  $Y = B(A + C) + C$  (ii)  $Y = (A + B)BC + A$  (06 Marks)
- c. Realize full adder circuit. Write truth table and expression for sum and carry. (08 Marks)

**Module-4**

- 7 a. Explain the working of NAND Gate latch using logic diagram and truth table. (06 Marks)
- b. Explain the working of RS flip-flop using logic diagram and truth table. (06 Marks)
- c. With block diagram, explain the architecture of 8051 Microcontroller. (08 Marks)

**OR**

- 8 a. Explain the working of clocked RS flip-flop using logic diagram and truth table. (07 Marks)
- b. Define microcontrollers. Write their important applications. (05 Marks)
- c. With block diagram, explain microcontroller based stepper motor control system. (08 Marks)

**Module-5**

- 9 a. Explain the block diagram of basic communication system. (06 Marks)
- b. Define amplitude modulation. Derive the mathematical expression for AM signal. (08 Marks)
- c. Explain the construction and the principle of operation of LVDT. (06 Marks)

**OR**

- 10 a. Explain the need for modulation. (06 Marks)
- b. Explain the principle of operation of piezoelectric transducer. (08 Marks)
- c. Write a short note on photoelectric transducers. (06 Marks)

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